

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

### IXTA05N100

### FEATURES

Static drain-source on-resistance:

 $R_{DS}(on) \le 17 \Omega @V_{GS} = 10V$ 

- · Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATION

SYMBOL

VDSS

- DC/DC Converter
- · Switch-Mode and Resonant-Mode Power Supplies

PARAMETER

VALUE

1000

1

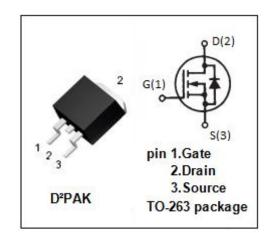
UNIT

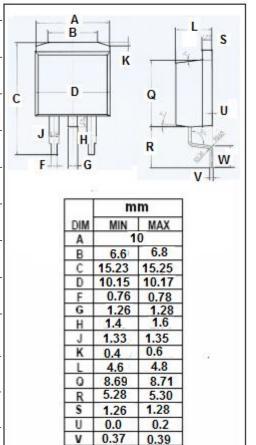
V

Uninterrupted Power Supplies

### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

Drain-Source Voltage





W 2.80

2.82

#### Gate-Source Voltage $\pm 30$ V V<sub>GS</sub> ΙD Drain Current-Continuous 0.75 А Drain Current-Single Pulsed 3 А Ірм Total Dissipation @Tc=25°C $\mathbf{P}_{\mathsf{D}}$ W 40 Τį **Operating Junction Temperature** -55~150 °C -55~150 °C Storage Temperature Tstg

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	3.125	°C <b>/W</b>



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	1000		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 250 μ A	2.5	4.5	V
$R_{DS(on)}$	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 0.375A		17	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		25	μΑ
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 125°C		500	
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 0.75A; V <sub>GS</sub> = 0V		1.5	V

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